# BLM8G0710S-30PB; BLM8G0710S-30PBG LDMOS 2-stage power MMIC

**AMMPLEON** 

Rev. 4 — 9 February 2018

Product data sheet

#### **Product profile**

#### 1.1 General description

The BLM8G0710S-30PB(G) is a dual section, 2-stage power MMIC using Ampleon's state of the art GEN8 LDMOS technology. This multiband device is perfectly suited as general purpose driver or small cell final in the frequency range from 700 MHz to 1000 MHz. Available in gull wing or straight lead outline.

#### Table 1. **Performance**

Typical RF performance at  $T_{case}$  = 25 °C;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA. Test signal: 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF; per section unless otherwise specified in a class-AB production circuit.

Test signal	f	V <sub>DS</sub>	P <sub>L(AV)</sub>	G <sub>p</sub>	η <sub>D</sub>	ACPR <sub>5M</sub>
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
single carrier W-CDMA	957.5	28	3	35	27	<b>-41.5</b>

#### 1.2 Features and benefits

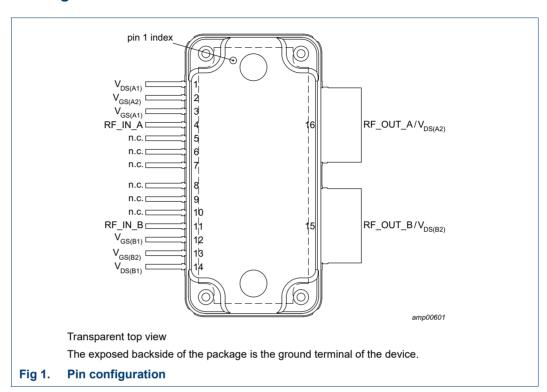
- Designed for broadband operation (frequency 700 MHz to 1000 MHz)
- High section-to-section isolation enabling multiple combinations
- Integrated temperature compensated bias
- Biasing of individual stages is externally accessible
- Integrated ESD protection
- Excellent thermal stability
- High power gain
- On-chip matching for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

#### 1.3 Applications

- RF power MMIC for W-CDMA base stations in the 700 MHz to 1000 MHz frequency range. Possible circuit topologies are the following as also depicted in Section 8.1:
  - Dual section or single ended
  - Doherty
  - Quadrature combined
  - Push-pull

### 2. Pinning information

#### 2.1 Pinning



#### 2.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V <sub>DS(A1)</sub>	1	drain-source voltage of driver stage A1
V <sub>GS(A2)</sub>	2	gate-source voltage of final stage A2
V <sub>GS(A1)</sub>	3	gate-source voltage of driver stage A1
RF_IN_A	4	RF input section A
n.c.	5	not connected
n.c.	6	not connected
n.c.	7	not connected
n.c.	8	not connected
n.c.	9	not connected
n.c.	10	not connected
RF_IN_B	11	RF input section B
V <sub>GS(B1)</sub>	12	gate-source voltage of driver stage B1
V <sub>GS(B2)</sub>	13	gate-source voltage of final stage B2
V <sub>DS(B1)</sub>	14	drain-source voltage of driver stage B1

Table 2. Pin description ...continued

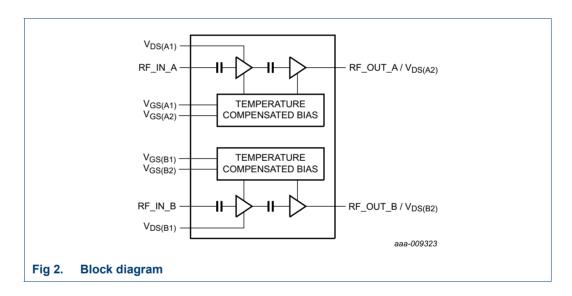
Symbol	Pin	Description
RF_OUT_B/V <sub>DS(B2)</sub>	15	RF output section B / drain-source voltage of final stage B2
RF_OUT_A/V <sub>DS(A2)</sub>	16	RF output section A / drain-source voltage of final stage A2
GND	flange	RF ground

### 3. Ordering information

Table 3. Ordering information

Type number	Packag	Package							
	Name	Description	Version						
BLM8G0710S-30PB	-	plastic, heatsink small outline package; 16 leads (flat)	SOT1211-3						
BLM8G0710S-30PBG	-	plastic, heatsink small outline package; 16 leads	SOT1212-3						

### 4. Block diagram



### 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C
T <sub>case</sub>	case temperature		-	150	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

#### 6. Thermal characteristics

Table 5. Thermal characteristics

Measured for total device.

Symbol	Parameter	Conditions		Value	Unit
11(1-0)		final stage; T <sub>case</sub> = 90 °C; P <sub>L</sub> = 2.52 W	[1]	1.5	K/W
	junction to case	driver stage; T <sub>case</sub> = 90 °C; P <sub>L</sub> = 2.52 W	[1]	5.3	K/W

<sup>[1]</sup> When operated with a CW signal.

#### 7. Characteristics

Table 6. DC characteristics

 $T_{\text{case}}$  = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Min	Тур	Max	Unit	
Final stag	je					-
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	V <sub>GS</sub> = 0 V; I <sub>D</sub> = 0.241 mA	65	-	-	V
$V_{GSq}$	gate-source quiescent voltage	V <sub>DS</sub> = 28 V; I <sub>D</sub> = 120 mA	1.5	2	2.7	V
		$V_{DS} = 28 \text{ V}; I_D = 120 \text{ mA}$	1.9	2.6	3.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	V <sub>GS</sub> = 5.65 V; V <sub>DS</sub> = 10 V	-	4.4	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 1.0 V; V <sub>DS</sub> = 0 V	-	-	140	nA
Driver sta	ige					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.06 \text{ mA}$	65	-	-	V
$V_{GSq}$	gate-source quiescent voltage	V <sub>DS</sub> = 28 V; I <sub>D</sub> = 30 mA	1.5	2.1	2.7	V
		$V_{DS} = 28 \text{ V}; I_D = 30 \text{ mA}$	1.9	2.6	3.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	V <sub>GS</sub> = 5.65 V; V <sub>DS</sub> = 10 V	-	1.1	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 1.0 V; V <sub>DS</sub> = 0 V	-	-	140	nA

<sup>[1]</sup> In production circuit with 1.3 k $\Omega$  gate feed resistor.

Table 7. RF Characteristics

Typical RF performance at  $T_{\rm case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA;  $P_{L(AV)}$  = 3 W. Per section unless otherwise specified, measured in an Ampleon wideband f = 700 MHz to 1000 MHz production circuit.

-1,						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test sign	nal: single carrier W-CDMA [1]					
Gp	power gain	f = 730.5 MHz	-	35.7	-	dB
		f = 957.5 MHz	33.5	35	36.5	dB
η <sub>D</sub>	drain efficiency	f = 730.5 MHz	-	24	-	%
		f = 957.5 MHz	23.5	27	-	%
RLin	input return loss	f = 730.5 MHz	-	-20	-	dB
		f = 957.5 MHz	-	-16	-10	dB
ACPR <sub>5M</sub>		f = 730.5 MHz	-	-39	-	dBc
	(5 MHz)	f = 957.5 MHz	-	-41.5	-38.5	dBc

BLM8G0710S-30PB\_S-30PBG

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<sup>[2]</sup> In production circuit with 1.2  $k\Omega$  gate feed resistor.

#### Table 7. RF Characteristics ...continued

Typical RF performance at  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA;  $P_{L(AV)}$  = 3 W. Per section unless otherwise specified, measured in an Ampleon wideband f = 700 MHz to 1000 MHz production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
PARO	output peak-to-average ratio	f = 730.5 MHz	-	8	-	dB
		f = 957.5 MHz	7.3	8	-	dB
$\Delta I_{Dq}/\Delta T$ quiescent drain current variation with		T = -40 °C to +85 °C				
	temperature	final stage $I_{Dq}$ ; gate feed resistor = 1.3 k $\Omega$	-	0.5	-	%
		driver stage $I_{Dq}$ ; gate feed resistor = 1.2 k $\Omega$	-	0.5	-	%
Test sign	al: CW [2]					
$\Delta\phi_{s21}$	phase response difference	between sections	-10	-	+10	deg
$\Delta  s_{21} ^2$	insertion power gain difference	between sections	-0.5	-	+0.5	dB

<sup>[1] 3</sup>GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01% probability on CCDF.

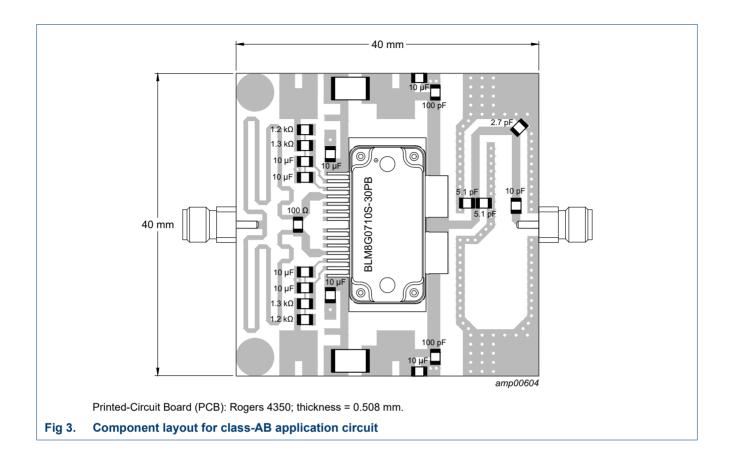
#### 8. Application information

#### Table 8. Typical performance

Test signal: 1-tone CW; RF performance at  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 60 mA (both sections);  $I_{Dq2}$  = 240 mA (both sections) unless otherwise specified, measured in an Ampleon wideband f = 700 MHz to 1000 MHz class AB application circuit.

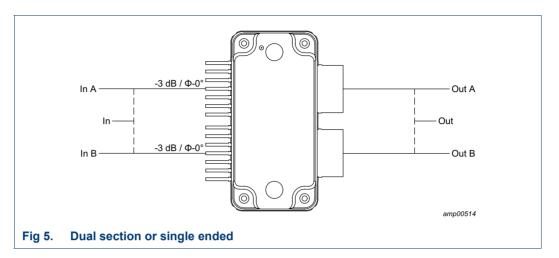
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	f = 800 MHz	-	29.7	-	W
$\eta_{D}$	drain efficiency	at P <sub>L(1dB)</sub> ; f = 800 MHz	-	51.7	-	%
G <sub>p</sub>	power gain	P <sub>L(AV)</sub> = 8 W; f = 800 MHz	-	35.8	-	dB
B <sub>video</sub>	video bandwidth	2-tone CW; P <sub>L(AV)</sub> = 16 W; f = 881 MHz	-	168	-	MHz
G <sub>flat</sub>	gain flatness	P <sub>L(AV)</sub> = 8 W	-	0.5	-	dB
ΔG/ΔT	gain variation with temperature	f = 800 MHz	-	0.03	-	dB/°C
s <sub>12</sub>   <sup>2</sup>	isolation	between sections A and B; P <sub>L(AV)</sub> = 8 W; f = 800 MHz	-	26	-	dB
K	Rollett stability factor	T = -40 °C; f = 0.1 GHz to 3 GHz	-	>1	-	

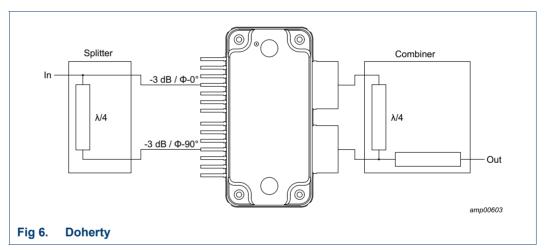
<sup>[2]</sup> f = 957.5 MHz.

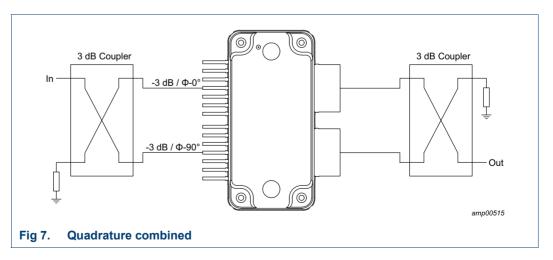


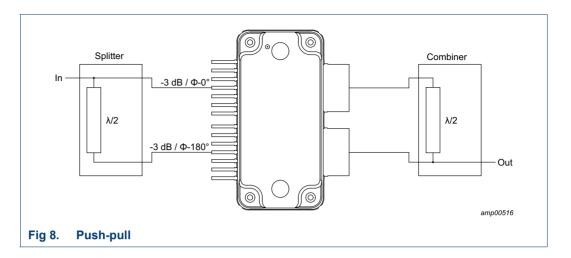
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#### 8.1 Possible circuit topologies









#### 8.2 Ruggedness in class-AB operation

The BLM8G0710S-30PB and BLM8G0710S-30PBG are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 32 V;  $I_{Dq1}$  = 40 mA;  $I_{Dq2}$  = 120 mA;  $P_i$  = 13 dBm,  $P_i$  is measured at CW and corresponding to  $P_{L(3dB)}$  under  $Z_S$  = 50  $\Omega$ ; f = 840 MHz.

#### 8.3 Impedance information

Table 9. Typical impedance tuned for maximum output power

Measured load-pull data per section; test signal: pulsed CW;  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA;  $I_{Dq}$  = 100 μs;  $\delta$  = 10 %;  $I_{Dq}$  = 50  $I_{Dq}$  . Typical values unless otherwise specified.

	at 1dB gain	compress	ion poin	nt		at 3dB gain compression point					
f	Z <sub>L</sub>	G <sub>p(max)</sub>	P <sub>L</sub>	η <sub>add</sub>	AM-PM conversion	Z <sub>L</sub>	G <sub>p(max)</sub>	P <sub>L</sub>	ηadd	AM-PM conversion	
(MHz)	<b>(</b> Ω <b>)</b>	(dB)	(dBm)	(%)	(deg)	<b>(</b> Ω <b>)</b>	(dB)	(dBm)	(%)	(deg)	
BLM8G	0710S-30PB										
680	6.1 + j5.1	34.2	44	56.2	-7.3	6.4 + j4.3	34	44.9	59.4	-9.2	
700	5.6 + j4.6	34	43.9	53.3	-6.8	6.2 + j3.6	33.9	44.8	56.4	-8.5	
720	6.1 + j5.2	34.5	43.8	56.7	-6.4	6.2 + j3.7	34	44.8	56.8	-8	
740	5.7 + j4.6	34.1	43.8	53.7	-5.3	6.3 + j3.6	33.9	44.8	57.2	-7.2	
760	5.7 + j4.5	34	43.8	54.6	-4.4	6.3 + j3.5	33.8	44.8	57.4	-6.1	
780	6.2 + j3.5	33.6	43.8	53.4	-3.6	6.2 + j3.5	33.6	44.8	57.7	-6.2	
800	7.0 + j3.3	33.7	43.9	55.6	-2.6	6.2 + j2.8	33.4	44.9	56.3	-5	
820	6.3 + j2.9	33.3	43.9	52.7	-3	6.3 + j2.9	33.3	44.8	56.8	-5.7	
840	6.3 + j2.8	33.2	43.9	53.3	-2.1	6.8 + j2.2	33.1	44.9	56.5	-4.1	
860	7.0 + j3.2	33.5	43.8	56	-2.2	7.4 + j1.7	33.1	44.8	56.2	-4	
880	6.7 + j2.1	33.1	43.8	52	-1.3	7.4 + j1.7	33.1	44.8	56.2	-3.3	
900	7.4 + j1.8	33.2	43.9	53.4	-1.2	7.2 + j0.9	32.9	44.8	54.3	-3.4	
920	6.8 + j2.2	33.3	43.8	53.1	-1	7.3 + j0.9	32.9	44.7	54.2	-2.7	
940	7.5 + j1.7	33.4	43.8	53.1	-0.5	8.1 + j0.7	33.2	44.7	55.2	-2	
960	7.2 + j0.9	33.2	43.6	49.7	-0.2	7.2 + j0.9	33.2	44.6	53.4	-2.4	
980	6.5 + j1.3	33.2	43.7	49.7	-0.3	8.0 + j0.8	33.4	44.7	55.1	-2	
1000	8.1 + j0.9	33.4	43.6	51.4	0.3	8.1 + j0.9	33.4	44.6	55.1	-2.2	
BLM8G	0710S-30PBG	)									
700	5.7 + j4.6	34.7	43.5	53.5	-7.3	6.4 + j3.1	34.4	44.4	55.3	-8.8	
720	5.8 + j3.8	34.6	43.5	52.1	-6	6.3 + j3.4	34.6	44.4	56.6	-8.3	
740	5.6 + j3.8	34.5	43.5	51.7	-6.2	6.5 + j2.6	34.4	44.5	55.5	-7.6	
760	6.1 + j3.2	34.3	43.5	52.5	-5	7.4 + j1.8	34.2	44.5	55.9	-6	
780	5.7 + j2.7	33.8	43.5	50.1	-4.1	6.5 + j1.6	33.6	44.5	53.1	-5.5	
800	6.4 + j2.2	33.7	43.7	52.7	-3.1	7.1 + j1.3	33.6	44.7	55.7	-4.8	
820	6.8 + j2.4	33.8	43.7	54.3	-2.6	6.4 + j1.2	33.3	44.7	54.2	-4.8	
840	7.0 + j0.8	33.3	43.7	51.2	-2.3	7.0 + j0.8	33.3	44.7	55	-4.7	
860	6.8 + j1.9	33.6	43.6	53.2	-2.5	7.5 + j0.5	33.3	44.6	54.7	-4.4	
880	6.6 + j1.3	33.5	43.5	50.8	-2	7.4 + j0.7	33.4	44.5	54.6	-4.3	
900	7.1 + j1.3	33.7	43.4	51.6	-1.2	8.2 + j0.3	33.6	44.4	54.8	-2.9	
920	7.4 + j0.0	33.4	43.4	49.4	-0.7	7.4 + j0.1	33.4	44.5	53.8	-2.8	
940	8.0 – j0.2	33.4	43.3	49.3	-0.2	8.0 + j0.1	33.5	44.4	53.9	-2.4	
960	7.8 + j0.7	34	43.3	51.1	0.1	7.9 – j0.6	33.5	44.3	52.4	-2	
980	7.7 – j0.5	33.7	43.3	48.6	0.5	7.7 – j0.5	33.7	44.4	53	-1.6	
1000	7.2 – j0.4	33.5	43.3	48.4	0.1	7.2 – j0.4	33.5	44.3	52.7	-2.3	

BLM8G0710S-30PB\_S-30PBG

## **BLM8G0710S-30PB(G)**

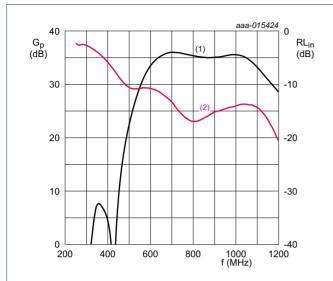
**LDMOS 2-stage power MMIC** 

Table 10. Typical impedance tuned for maximum power added efficiency

Measured load-pull data per section; test signal: pulsed CW;  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA;  $I_{p}$  = 100 μs;  $\delta$  = 10 %;  $I_{p}$  = 50  $I_{p}$ . Typical values unless otherwise specified.

	at 1dB gain	compress	ion poin	ıt		at 3dB gain compression point					
f	Z <sub>L</sub>	G <sub>p(max)</sub>	PL	ηadd	AM-PM conversion	Z <sub>L</sub>	G <sub>p(max)</sub>	PL	ηadd	AM-PM conversion	
(MHz)	<b>(</b> Ω <b>)</b>	(dB)	(dBm)	(%)	(deg)	<b>(</b> Ω <b>)</b>	(dB)	(dBm)	(%)	(deg)	
BLM8G	0710S-30PB						,				
680	9.6 + j9.3	35.5	42.6	65.9	-8.9	9.3 + j8.4	35.3	43.6	68.1	-11.1	
700	8.7 + j9.5	35.6	42.5	65.4	-9	9.2 + j8.5	35.5	43.5	67.3	-10.7	
720	8.8 + j9.6	35.7	42.3	64.5	-8	8.8 + j9.6	35.7	43	67	<b>–11</b>	
740	8.0 + j9.5	35.6	42.3	64.2	-7.3	8.5 + j8.7	35.4	43.3	66.7	-9.7	
760	8.9 + j9.4	35.5	42.3	64.5	-5.5	9.4 + j8.4	35.3	43.3	66.7	-7.3	
780	8.4 + j8.5	35.1	42.5	63.8	-5	8.4 + j8.5	35.1	43.2	66.1	-8.2	
800	8.4 + j8.6	35.1	42.4	63.5	-4.2	9.2 + j8.5	35.1	43.2	65.4	-6.1	
820	8.4 + j8.7	34.9	42.3	62.7	-4.1	8.7 + j6.8	34.6	43.7	65.1	-6.3	
840	8.5 + j8.6	34.9	42.3	63	-3.1	7.9 + j6.9	34.6	43.7	65.1	-6.2	
860	8.5 + j8.5	34.8	42.2	62.1	-2.9	7.9 + j6.8	34.5	43.7	64.5	-6.2	
880	7.6 + j8.5	34.8	42.1	61.8	-3	7.8 + j6.8	34.5	43.6	64	-5.3	
900	8.0 + j7.7	34.7	42.4	61.9	-2.3	7.8 + j6.8	34.6	43.5	63.8	-5.2	
920	8.7 + j6.8	34.6	42.7	61.2	-1	8.1 + j7.8	34.8	43.1	63.1	-3.9	
940	8.2 + j7.7	34.9	42.2	60.6	-1.3	8.3 + j5.9	34.6	43.7	62.4	-2.8	
960	7.9 + j6.8	34.9	42.4	59.3	-1.1	8.7 + j6.7	34.8	43.3	61.8	-1.9	
980	7.5 + j8.5	35.2	41.7	59.8	-1	8.6 + j6.8	34.8	43.3	62.1	-1.5	
1000	8.0 + j7.8	35	41.9	59.1	-0.2	7.1 + j6.8	34.9	43.1	61.6	-3.2	
BLM8G	0710S-30PBG	;	1			1					
700	8.4 + j8.2	36	42.3	63.4	-9	8.5 + j8.5	36.1	42.9	65.8	-12.7	
720	8.6 + j9.1	36.2	41.9	63.9	-8.1	8.9 + j8.8	36.1	42.8	66.8	-11	
740	8.3 + j8.2	36	42.2	62.6	-7.6	8.3 + j8.2	36	42.9	65.4	-10.9	
760	9.6 + j7.7	35.7	42.2	62.2	-5.4	8.8 + j8.7	35.9	42.6	65.1	-9.2	
780	8.5 + j7.1	35.4	42.4	61.5	-5.1	7.3 + j8.1	35.5	42.7	64.2	-10.2	
800	8.0 + j8.3	35.5	41.8	62.1	-4.8	7.1 + j8.0	35.5	42.8	64.9	-9.7	
820	8.0 + j7.1	35.1	42.3	61.6	-4	8.3 + j8.2	35.3	42.6	64	-6.9	
840	8.8 + j7.2	35.1	42.1	61.4	-3.4	8.1 + j8.1	35.3	42.5	63.5	-7	
860	8.4 + j7.1	35.1	42.1	60.9	-3.3	8.4 + j7.1	35.1	42.9	63.4	-6	
880	8.1 + j6.4	35.1	42.2	60.1	-2.9	8.2 + j7.4	35.3	42.7	62.3	-6	
900	7.3 + j6.2	35.2	42.1	59.5	-2.8	8.0 + j7.2	35.4	42.6	62.1	-4.9	
920	8.0 + j7.4	35.4	41.6	59.5	-2.1	7.3 + j6.3	35.3	42.9	61.8	-5.4	
940	8.1 + j6.6	35.3	41.8	58.7	-1.5	6.8 + j6.5	35.4	42.6	60.9	-5.7	
960	9.5 + j5.4	35.2	42.2	57.8	0	7.0 + j6.9	35.8	42.4	60.5	-4.2	
980	8.1 + j6.5	35.4	41.7	58.1	-0.3	7.1 + j6.3	35.5	42.6	61.3	-3	
1000	6.9 + j4.9	35	42.2	58.2	-1.1	7.0 + j6.0	35.2	42.7	61.1	-3.2	

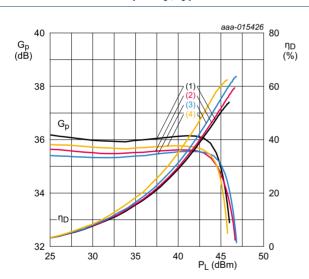
#### 8.4 Graphs



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA;  $P_{I}$  = 0.25 W. Per section.

- (1) magnitude of G<sub>p</sub>
- (2) magnitude of RLin

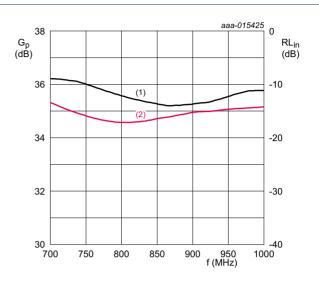
Fig 9. Wideband power gain and input return loss as function of frequency; typical values



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA. Per section.

- (1) f = 700 MHz
- (2) f = 800 MHz
- (3) f = 900 MHz
- (4) f = 1000 MHz

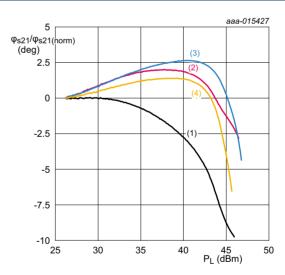
Fig 11. Power gain and drain efficiency as function of output power; typical values



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA;  $P_I$  = 0.25 W. Per section.

- (1) magnitude of G<sub>p</sub>
- (2) magnitude of RLin

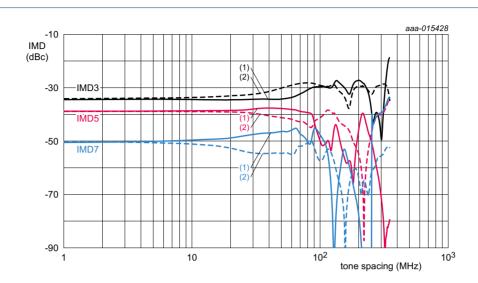
Fig 10. In-band power gain and input return loss as function of frequency; typical values



Normalized at P<sub>L</sub> = 26 dBm;  $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA. Per section.

- (1) f = 700 MHz
- (2) f = 800 MHz
- (3) f = 900 MHz
- (4) f = 1000 MHz

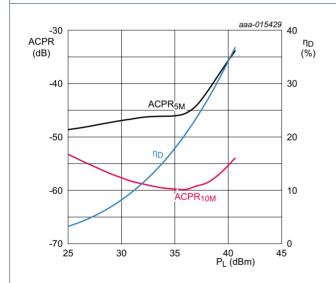
Fig 12. Normalized phase response as a function of output power; typical values



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA; f = 881 MHz; 2-tone CW;  $P_L$  = 8 W. Per section.

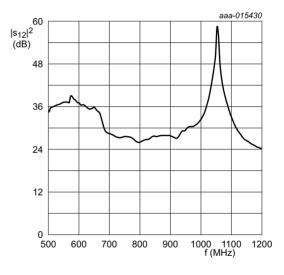
- (1) IMD low
- (2) IMD high

Fig 13. Intermodulation distortion as a function of tone spacing; typical values



 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA; f = 900 MHz; 1-carrier W-CDMA; test model 1; PAR = 9.9 dB at 0.01 % probability on CCDF. Per section.





 $T_{case}$  = 25 °C;  $V_{DS}$  = 28 V;  $I_{Dq1}$  = 30 mA;  $I_{Dq2}$  = 120 mA; measured on evaluation board.

Fig 15. Isolation as a function of frequency; typical values

### 9. Package outline

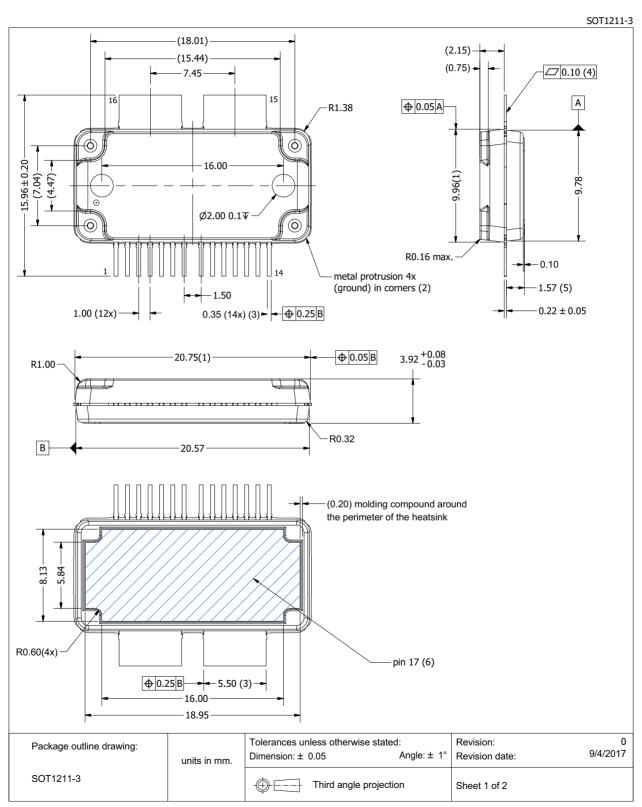


Fig 16. Package outline SOT1211-3 (sheet 1 of 2)

#### SOT1211-3

	Drawing Notes			
Items	Description			
	Dimensions are excluding mold protrusion. Areas located adjacent to the leads have a maximum mold protrusion of 0.25			
(1)	mm (per side) and 0.62 mm max. in length. In between the 14 leads the protrusion is 0.25 mm. max. At all other areas the			
	mold protrusion is maximum 0.15 mm per side. See also detail B.			
(2)	The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A).			
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.			
(4)	The lead coplanarity over all leads is 0.1 mm maximum.			
(5)	Dimension is measured 0.5 mm from the edge of the top package body.			
(6)	The hatched area indicates the exposed metal heatsink.			
(7)	The leads and exposed heatsink are plated with matte Tin (Sn).			

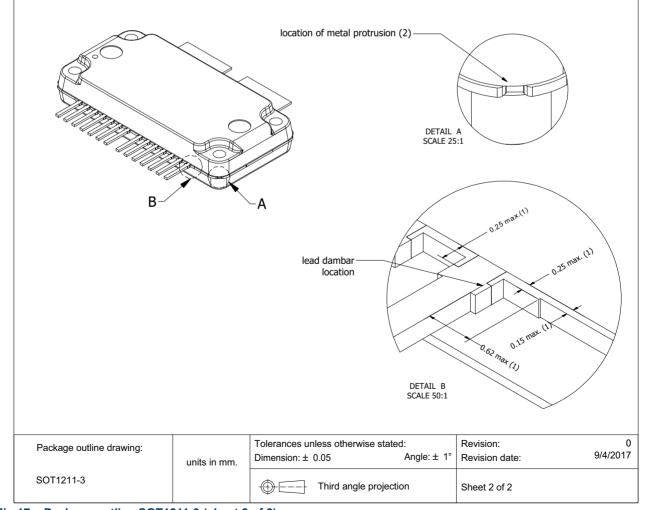


Fig 17. Package outline SOT1211-3 (sheet 2 of 2)

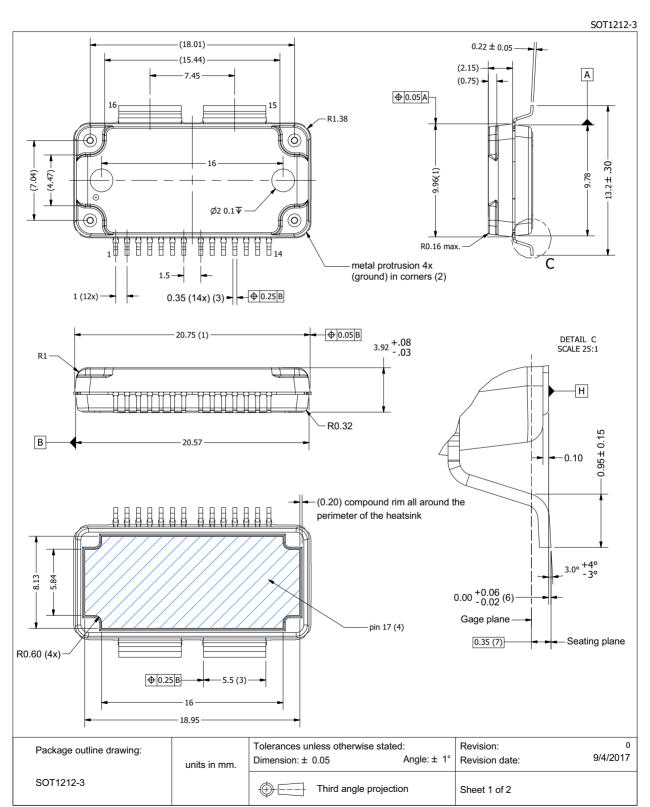


Fig 18. Package outline SOT1212-3 (sheet 1 of 2)

#### SOT1212-3

	Drawing Notes
Items	Description
	Dimensions are excluding mold protrusion. Areas located adjacent to the leads have a maximum mold protrusion of 0.25
(1)	mm (per side) and 0.62 mm max. in length. In between the 14 leads the protrusion is 0.25 mm max. At all other areas the
	mold protrusion is maximum 0.15 mm per side. See also detail B.
(2)	The metal protrusion (tie bars) in the corner will not stick out of the molding compound protrusions (detail A).
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location
(4)	The hatched area indicated the exposed heatsink.
(5)	The leads and exposed heatsink are plated with matte Tin (Sn).
(0)	Dimension is measured with respect to the bottom of the heatsink Datum H. Positive value means that the bottom of the
(6)	heatsink is higher than the bottom of the lead.
(7)	Gage plane (foot length) to be measured from the seating plane.

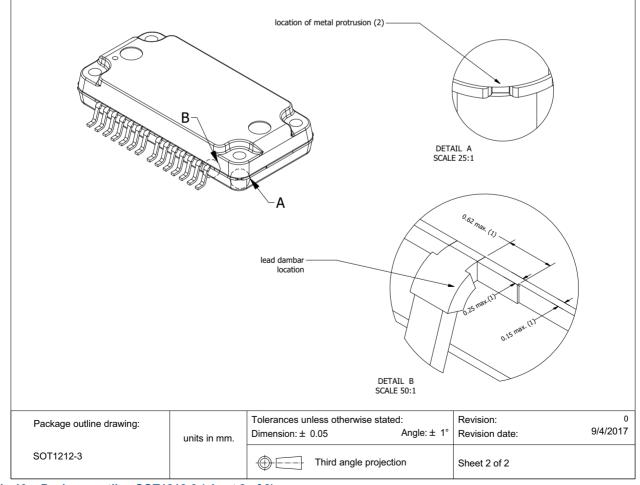


Fig 19. Package outline SOT1212-3 (sheet 2 of 2)

### 10. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C1 [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	1A [2]

- [1] CDM classification C1 is granted to any part that passes after exposure to an ESD pulse of 250 V, but fails after exposure to an ESD pulse of 500 V.
- [2] HBM classification 1A is granted to any part that passes after exposure to an ESD pulse of 250 V, but fails after exposure to an ESD pulse of 500 V.

#### 11. Abbreviations

Table 12. Abbreviations

Acronym	Description
AM	Amplitude Modulation
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
GEN8	Eighth Generation
LDMOS	Laterally Diffused Metal Oxide Semiconductor
MMIC	Monolithic Microwave Integrated Circuit
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
PM	Phase Modulation
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

### 12. Revision history

#### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM8G0710S-30PB_S-30PBG v.4	20180209	Product data sheet		BLM8G0710S-30PB_ S-30PBG v.3
Modifications:	<ul> <li>Table 3 on SOT1212-3</li> <li>Figure 3 on</li> <li>Figure 5 on</li> <li>Figure 6 on</li> <li>Figure 8 on</li> <li>Table 9 on</li> <li>Table 10 or</li> <li>Section 9 or</li> <li>SOT1212-2</li> </ul>	page 6: figure updated page 8: figure updated page 8: figure updated page 8: figure updated page 9: figure updated page 10: typo corrected page 11: typo corrected page 14: package outline to SOT1211-3 and SOT12	e versions changed	
BLM8G0710S-30PB_S-30PBG v.3	20150901	Product data sheet		BLM8G0710S-30PB_ S-30PBG v.2
BLM8G0710S-30PB_S-30PBG v.2	20150701	Product data sheet	-	BLM8G0710S-30PB_ S-30PBG v.1
BLM8G0710S-30PB_S-30PBG v.1	20150123	Product data sheet	-	-

#### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BLM8G0710S-30PB S-30PBG

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## **BLM8G0710S-30PB(G)**

#### LDMOS 2-stage power MMIC

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### **AMPLEON**

## **BLM8G0710S-30PB(G)**

**LDMOS 2-stage power MMIC** 

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